## 1. Scope

The present specifications shall apply to an RD2A.

## 2. Outline

|       | Туре                                | Silicon Diode                |  |  |  |  |  |
|-------|-------------------------------------|------------------------------|--|--|--|--|--|
|       | Structure                           | re Resin Molded              |  |  |  |  |  |
|       | Applications                        | High Frequency Rectification |  |  |  |  |  |
| 3. F  | Flammability<br>UL94V-0(Equivalent) |                              |  |  |  |  |  |
|       | Flammability<br>UL94V-0(Equivalent) |                              |  |  |  |  |  |
|       | endedte                             |                              |  |  |  |  |  |
|       | Recommended for New Y               |                              |  |  |  |  |  |
| Aotre |                                     |                              |  |  |  |  |  |

### 3. Flammability

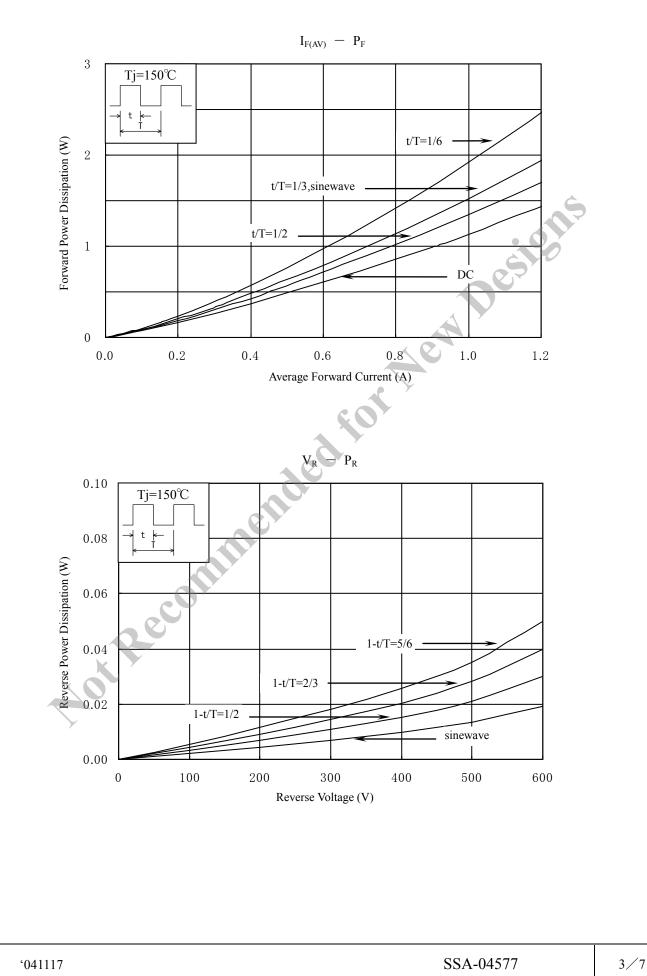
## 4. Absolute maximum ratings

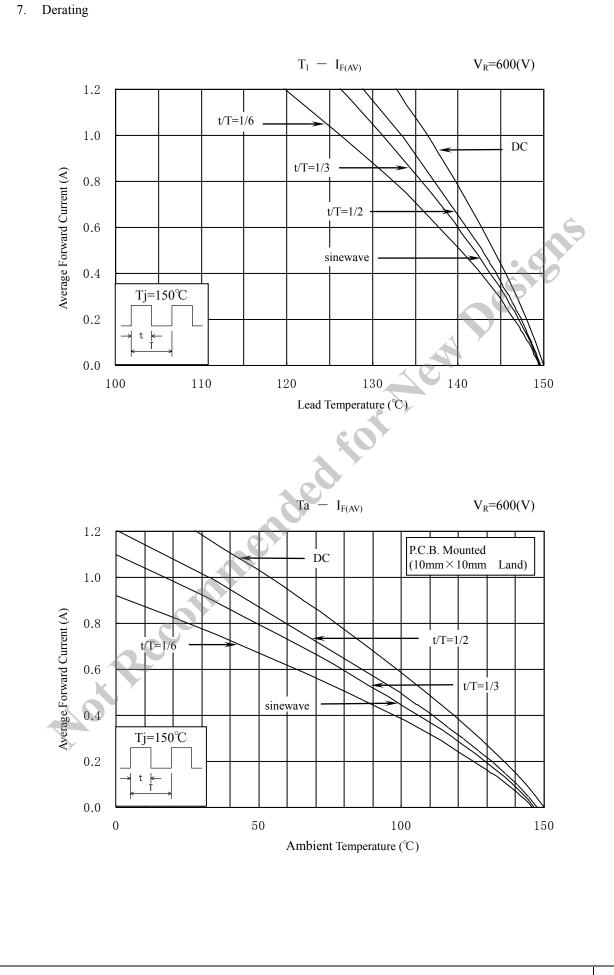
| No. | Item                            | Symbol             | Unit             | Rating   | Conditions   |
|-----|---------------------------------|--------------------|------------------|----------|--|
| 1   | Transient Peak Reverse Voltage  | V <sub>RSM</sub>   | V                | 600      |  |
| 2   | Peak Reverse Voltage            | V <sub>RM</sub>    | V                | 600      |  |
| 3   | Average Forward Current         | I <sub>F(AV)</sub> | А                | 1.2      | Refer to Derating of 7                                     |
| 4   | Peak Surge Forward Current      | I <sub>FSM</sub>   | А                | 30       | 10msec.<br>Half sinewave, one shot                         |
| 5   | I <sup>2</sup> t Limiting Value | I <sup>2</sup> t   | A <sup>2</sup> s | 4.5      | $1 \operatorname{msec} \leq t \leq 10 \operatorname{msec}$ |
| 6   | Junction Temperature            | Tj                 | °C               | -40~+150 | 6  |
| 7   | Storage Temperature             | T <sub>stg</sub>   | °C               | -40~+150 | 0  |

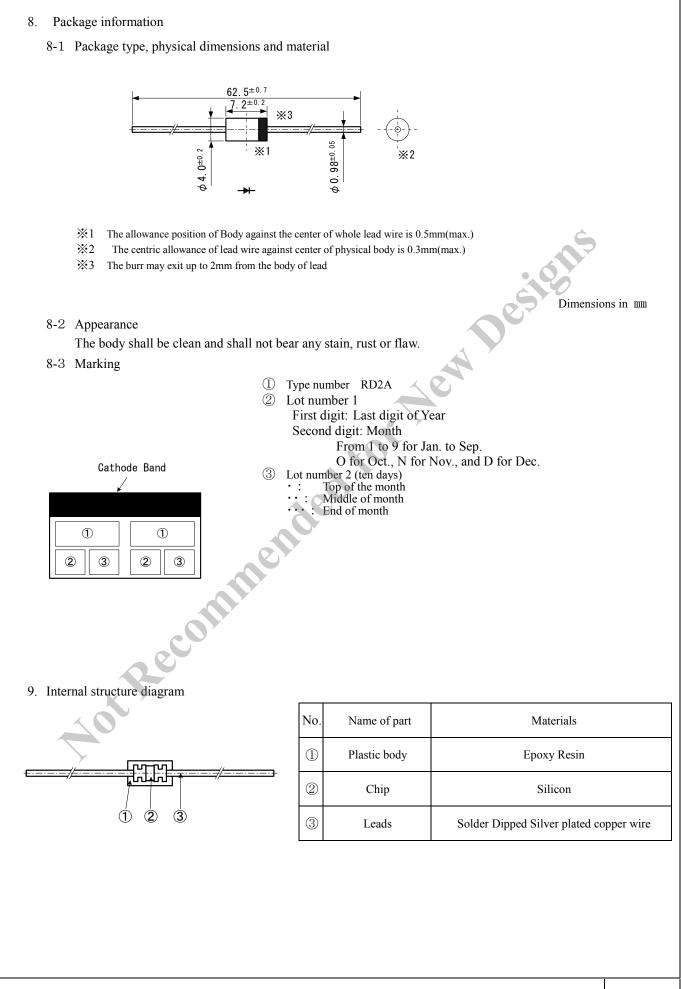
### 5. Electrical characteristics

| No. | Item  | Symbol                    | Unit | Value     | Conditions   |
|-----|---|---------------------------|------|-----------|--|
| 1   | Forward Voltage Drop                              | $\mathbf{V}_{\mathrm{F}}$ | V    | 1.55 max. | $I_F=1.2A$   |
| 2   | Reverse Leakage Current                           | I <sub>R</sub>            | uA   | 50 max.   | V <sub>R</sub> =V <sub>RM</sub>  |
| 3   | Reverse Leakage Current Under<br>High Temperature | H•I <sub>R</sub>          | uA   | 100 max.  | $V_R = V_{RM}, T_j = 150^{\circ}C$   |
| 4   | Reverse Recovery Time                             | t <sub>rr</sub> 1         | ns   | 50 max.   | $I_F = I_{RP} = 100 \text{mA}$<br>90% Recovery point, $T_j = 25^{\circ}\text{C}$ |
| 4   | Reverse Recovery Time                             | t <sub>rr</sub> 2         | ns   | 35 max.   | $I_F$ =100mA, $I_{RP}$ =200mA<br>75% Recovery point, $T_j$ =25°C                 |
| 5   | Thermal Resistance                                | $R_{th(j-l)}$             | °C/W | 12 max.   | Between Junction and Lead  |
|     | totret  |                           |      |           |  |

## 6. Characteristics







# 10. Reliability

| 0. Reliability |                                    |             |  |  |  |  |
|----------------|------------------------------------|-------------|--|--|--|--|
| No.            | Item                               | Rating      | Conditions   |  |  |  |
| 1              | Thermal Fatigue Test               | 5000 cycles | ⊿Tj=100°C  |  |  |  |
| 2              | High Temperature Reverse Bias Test | 1000 hours  | Ta=150°C, $V_R = V_{RM}$ (Half sine wave)                |  |  |  |
| 3              | Humidity Reverse Bias Test         | 500 hours   | Ta=85°C, R.H.=85%, $V_R=V_{RM} \times 0.8(D.C.)$         |  |  |  |
| 4              | High Temperature Storage Test      | 1000 hours  | Ta=150°C   |  |  |  |
| 5              | Moisture Resistance Test           | 1000 hours  | Ta=85°C, 85%R.H  |  |  |  |
| 6              | Thermal Shock Test                 | 100 cycle   | Ice-water(5min.) ~ R.T.(20sec.) ~ Boiling-water(5min.)   |  |  |  |
| 7              | Temperature Cycle Test             | 100 cycle   | -40°C(30min.) ~ +150°C(30min.)                           |  |  |  |
| 8              | Pressure Cooker Test               | 96 hours    | $2.03 \times 10^{5}$ Pa, 100%R.H., Unsaturated equipment |  |  |  |
| 9              |                                    | 10 sec.     | $260\pm5^{\circ}$ C, Dipping up to 1.5mm form case       |  |  |  |
|                | Resistance to Soldering Heat Test  | 3.5 sec.    | 380±5℃, Using soldering iron                             |  |  |  |
| 10             | Solderability Test                 | 95%         | $245\pm5^{\circ}$ C, $5\pm0.5$ sec., Using rosin flux    |  |  |  |
| 11             | Lead Bend Test                     | 2 cycles    | Y  |  |  |  |
| 12             | Lead Pull Test                     | 10 sec.     | Apply EIAJ ED-4701 A-111                                 |  |  |  |
| 13             | Lead Twist Test 2 times            |             |  |  |  |  |
| 14             | Drop Test                          | 10 times    | Naturally drop from 1m height on maple plate             |  |  |  |

Acceptance Criteria

(1)Item No.1~9 The product shall meet the electrical specifications in paragraph 5

(2)Item No.10 after being exposed to normal temperature for less than 24 hours in 2 hours or more (2)Item No.10 The product shall meet the rating.

(3)Item No.11~14 There shall be no trouble in testing and the electrical characteristics in paragraph 5 shall be met.

#### 11. Cautions and warnings

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In addition, it should be noted that since power devices or IC's including power devices have large self-heating value, the degree of derating of junction temperature (Tj) affects the reliability significantly.

- When using the products specified herein by either (i) combining other products or materials therewith or (ii) physically, chemically or otherwise processing or treating the products, please duly consider all possible risks that may result from all such uses in advance and proceed therewith at your own responsibility.
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